

## kSEMAWc software

### Functions for the complex refractive index modeling

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# Basic relations among $\tilde{n}, \, \tilde{\chi}, \, \tilde{\epsilon}$



The theories for the light-matter interaction give the simplest expression for the complex dielectric susceptibility  $\tilde{\chi} = \chi_1 - i \chi_2$ .

Refractive index, dielectric susceptibility and permittivity  $\tilde{\epsilon} = \epsilon_1 - i \epsilon_2$  are connected by the following simple equations:

$$\tilde{\epsilon} = (n - ik)^2 = 1 + \tilde{\chi}.$$

Therefore:

$$\epsilon_1 = 1 + \chi_1, \qquad \epsilon_2 = \chi_2.$$

and:

$$n = \frac{1}{\sqrt{2}} \sqrt{\sqrt{\epsilon_1^2 + \epsilon_2^2 + \epsilon_1}}, \qquad k = \frac{1}{\sqrt{2}} \sqrt{\sqrt{\epsilon_1^2 + \epsilon_2^2 - \epsilon_1}}.$$

### Oscillator normalization



Inside kSEMAWc  $\tilde{\epsilon}$  is calculated as a sum of "oscillators"  $\tilde{\chi}_i$ corresponding to different groups of electronic transitions:

$$\tilde{\epsilon} = 1 + \sum_{i} \tilde{\chi}_{i} = 1 + \sum_{i} C_{i} \tilde{f}_{i}$$

Sum rule on  $\chi_2$ :

$$\int_0^\infty \chi_2(E)EdE = \frac{\pi(\hbar q)^2 N}{2\epsilon_0 m_e} = \frac{N(cm^{-3})}{4.61706 \cdot 10^{20}} eV^2$$

where N is electron number per unit volume of the material (all of them, including the core electrons), q is the electron charge and  $m_e$  is the electron mass.

As far as possible, the oscillator functions  $f_i$  in kSEMAWc are normalized according to:

$$\int_{0}^{\infty} Im(\tilde{f}_{i}(E))EdE = 1$$

"ideal global fit  $(0 < E < \infty)$ "  $\sum_{i} C_i = \frac{\pi (\hbar q)^2 N}{2\epsilon_0 m_e}$ 

$$\sum_{i} C_{i} = \frac{\pi (\hbar q)^{2} \Lambda}{2\epsilon_{0} m_{e}}$$

### The Flat Oscillator



Generally the fit is limited to energies lower than a few eV.

Transitions at higher energies, not explicitly included in the oscillator sum, give anyway a substantial contribute to  $\epsilon_1$ .

To simplify the fit, the 1 is replaced with a user-selectable parameter  $C_{flat}^2$ :

$$\tilde{\epsilon} = C_{flat}^2 + \sum_{i} \tilde{\chi}_i = C_{flat}^2 + \sum_{i} C_i \tilde{f}_i$$

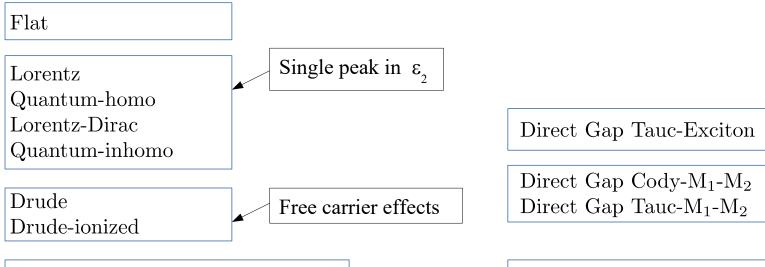
 $C_{flat}$  is the only parameter of a special "flat" oscillator and, since it is squared to obtain  $\epsilon_1$ ,  $C_{flat}$  corresponds fairly well to the refractive index offset generated by this "Flat" oscillator:  $n \simeq C_{flat} + \ldots$ 

A "flat" oscillator with  $C_{flat} > 1$  must be always included in the fit

### Oscillators available in ksemawc v2.6



 $\tilde{\epsilon}(E)$  is calculated summing up to 20 oscillators belonging to the following 18 classes:



Direct Gap Cody-Lorentzian tail
Direct Gap Tauc-Lorentzian tail
Indirect Gap Cody-Lorentzian tail
Indirect Gap Tauc-Lorentzian tail

Direct Gap Cody-Urbach (exponential) tail
Direct Gap Tauc-Urbach (exponential) tail
Indirect Gap Cody-Urbach (exponential) tail
Indirect Gap Tauc-Urbach (exponential) tail

## Oscillators parameters



All the oscillators have less than four free parameters.

|                        | C (eV <sup>2</sup> ) | E0 (eV)     | D                                   | W(eV)          |
|------------------------|----------------------|-------------|-------------------------------------|----------------|
| Flat                   | C >1                 | -           | -                                   | -              |
| Single peak            | intensity            | Peak energy | Line width                          | -              |
| Lorentz-Dirac          | intensity            | Peak energy | Line width                          | Line asymmetry |
| Drude                  | intensity            | -           | Line width                          | -              |
| Dir/Indir. Gap Lorentz | intensity            | Eg          | Line width                          | Band width     |
| Dir/Indir. Gap Urbach  | intensity            | Eg          | Urbach tail                         | Band width     |
| Dir. Gap Exciton       | intensity            | Eg          | Line width                          | Binding energy |
| Dir. Gap M1-M2         | intensity            | Eg          | (E <sub>1</sub> -E <sub>2</sub> )/2 | Band width     |

## Single peak oscillators formulas



"Lorentz"

$$\tilde{\chi} = \frac{2C}{\pi} \left[ \frac{1}{E_0^2 - E^2 + 2iED} \right]$$

"Quantum-homo"

$$\tilde{\chi} = \frac{C}{\pi E_0} \left[ \frac{1}{E_0 - E + iD} \right]$$

"Lorentz-Dirac"

$$\tilde{\chi} = \frac{2C}{\pi} \left[ \frac{1}{E_0^2 - E^2 + 2iE(D + E^2/W)} \right]$$

"Quantum-inhomo"

$$\tilde{\chi} = \frac{C}{K} \left\{ \frac{2}{\sqrt{\pi}} D_{+} \left( \frac{E_0 - E}{D/\sqrt{\ln 2}} \right) - i \cdot exp \left[ - \left( \frac{E - E_0}{D/\sqrt{\ln 2}} \right)^2 \right] \right\}$$

 $C = (\pi \hbar^2 q^2 N)/(2m\epsilon_0)$  is the oscillator amplitude with dimensions [eV]<sup>2</sup>

 $E_0$  is the resonance energy.

D is the line width.

W is the asymmetry parameter for the Lorentz-Dirac oscillator

 $D_{+}$  is the Dawson function

K is a normalization constant for the Quantum-inhomo oscillator

## Single peak oscillators



**Lorentz**: standard function for the fit of peak shaped absorption spectra. Its long tails may cause problems if used for materials with a high transparency in adjacent energy range.

**Quantum-homo**: obtained neglecting a not-resonant term in the Lorentz oscillator. Its simpler expression allows to obtain analytical results in convolution calculations.

Lorentz-Dirac: asymmetric line shape. Useful for the fitting of noble metals optical costants.

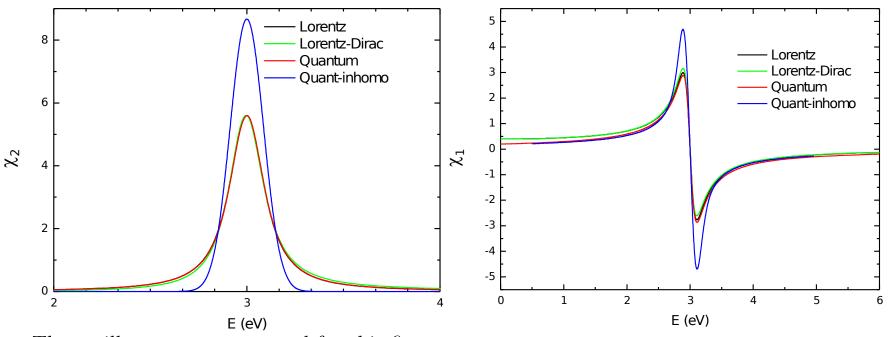
**Quantum-inhomo**: obtained as the convolution between a quantum oscillator and a Gaussian distribution centered in  $E_0$  and with HWHM equal to D; the line width of the quantum oscillator is assumed to be much lower than the Gaussian width.

Useful to model a set of absorbing centres which cannot be considered as identical replicas due, for example, to proximity to other randomly distributed defects or to random fluctuations of strain (inhomogeneous broadening).

The fast decay of its  $\chi_2$  away from the resonance energy avoid some problems encountered using the Lorentz oscillator.

## Comparison of the 4 single oscillators





The oscillator parameter used for this figure are:

C=5.6 eV<sup>2</sup> and  $E_0 = 3$  eV.

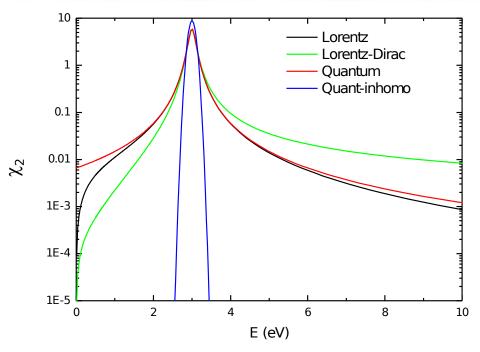
D=0.1 eV for Lorentz, Quantum and Quantum-inhomo oscillators.

D=0.01 eV and W=50 eV for Lorentz-Dirac oscillator.



# Comparison of $\chi_2$ for the 4 single oscillators





 $\chi_2$  for the 4 single peak oscillators (Lorentz, Lorentz-Dirac, Quantum and Quantum-inhomo) with C=5.6 eV<sup>2</sup> and  $E_0 = 3$  eV.

D=0.1 eV for Lorentz, Quantum and Quantum-inhomo oscillators.

D=0.01 eV and W=50 eV for Lorentz-Dirac oscillator.



### Drude oscillators



The "Drude" oscillator describes fairly well the response of a free electron gas. It can be obtained simply setting  $E_0 = 0$  in the Lorentz oscillator:

$$\chi_1 = -\frac{2C}{\pi} \frac{1}{D^2 + E^2}, \qquad \chi_2 = \frac{2C}{\pi} \frac{D}{E(D^2 + E^2)}.$$

D is related to the carrier scattering time  $\tau$  by  $D = \hbar/\tau$ .

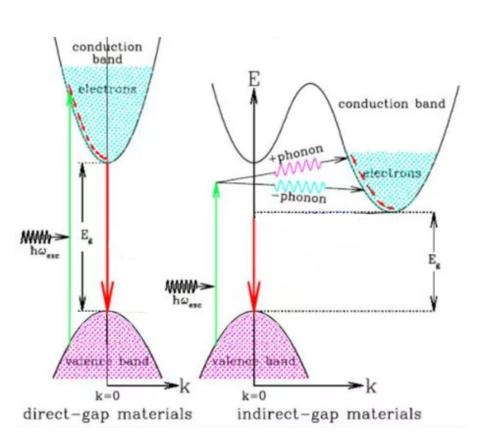
The optical mobility can be deduced from D using the equation  $\mu = q\tau/m^* = (q\hbar)/(m^*D)$ .

 $C = (\pi \hbar^2 q^2 N)/(2m^* \epsilon_0)$  where N is the carrier density and  $m^*$  is their effective mass.

A slightly modified version ("Drude-ionized") is available where D has an energy dependence (D(E)) to approximate the energy dependence of the carrier scattering time when the scattering is caused by ionized impurities.

## Direct and Indirect gap oscillators





The oscillators introduced up to now are unsuitable to describe the optical constants of systems with a continuous distribution of density of states such as semiconductors.

The theories reported in textbooks on semiconductors usually derive  $\chi_2$  only and exclusively at energies near the fundamental gap.

The calculation is made by hypothesizing that the excited states have infinite lifetime, i.e. that every transition between two states may take place only by absorbing/emitting photons and phonons with a total energy exactly equal to the difference of their energetic levels.

# $\chi_2^{inf}$ for excited states with infinite lifetime



#### Joint density of states

Calling  $\chi_2^{inf}$  the  $\chi_2$  calculated for excited states with infinite lifetime, we have for **direct transitions**:

$$\chi_2^{inf}(\hbar\omega) \propto C^{abs} \frac{|M_{cv}|^2}{\omega^2} \int_{E_C(k)-E_V(k)-\hbar\omega} \frac{dS}{\left|\vec{\nabla}(E_C(k)-E_V(k))\right|}$$

For **indirect transitions**:

$$\chi_2^{inf}(\hbar\omega) \propto C^{abs} \frac{|M_{cv}|^2}{\omega^2} \int_{E_g}^{\hbar\omega + \hbar\omega_k} G_C(E_f - E_g) G_V(\hbar\omega + \hbar\omega_k - E_f) dE_f$$

Conduction and valence band convolution

## Tauc and Cody approximations



Tauc approximation  $\iff$  constant momentum matrix element  $|M_{cv}|^2$ 

A constant  $|\langle r \rangle|^2$  assumption can be also used as proposed by Cody for the amorphous semiconductor case.

A relation between the matrix elements of these two operators can be obtained by using commutator relations:

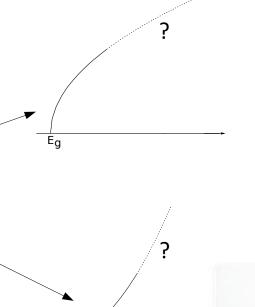
$$|\langle r \rangle|^2 = |M_{cv}|^2 \left(\frac{\hbar}{mE}\right)^2$$

## Energy dependence near Eg



If the bands are parabolic:

|              | Tauc  | Cody   |
|--------------|---|--|
| Direct gap   | $\chi_2^{inf}(E) \propto \frac{ M_{cv} ^2}{E^2} \sqrt{E - E_g}$         | $\chi_2^{inf}(E) \propto  \langle r \rangle ^2 \sqrt{E - E_g}$ |
| Indirect gap | $\chi_2^{inf}(E) \propto \frac{\left M_{cv}\right ^2}{E^2} (E - E_g)^2$ | $\chi_2^{inf}(E) \propto  \langle r \rangle ^2 (E - E_g)^2$    |



 $E_g$ 

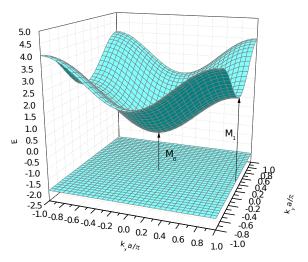
### 3D critical points



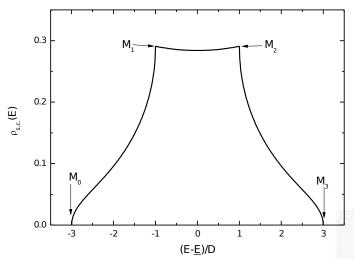
In 3 dimensions the Joint Density of States can show four types of critical points where  $\vec{\nabla}(E_C(k) - E_V(k)) = 0$ :  $M_0(\text{minimum})$ ,  $M_1(\text{saddle})$ ,  $M_2(\text{saddle})$ ,  $M_3(\text{maximum})$ .

Band for a simple cubic lattice in the Tight-Binding s-level nearest-neighbor approximation with an overlap integral equal to D:

$$E(\vec{k}) = E_{lev} - 2D[cos(k_x a) + cos(k_y a) + cos(k_z a)]$$



Plot for the 2-D case

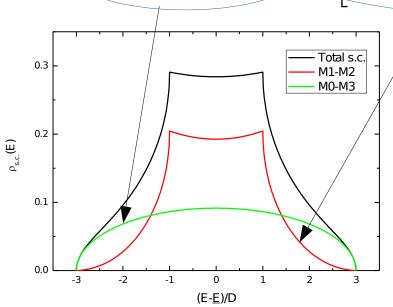


Density of states for the 3-D case

## 3D critical points: analytical approximation



$$\rho_{s.c.}(E) = A\sqrt{(E - E_0)(E_3 - E)} + B\left[\sqrt{\frac{W}{2} - D} - \Theta(|E - \overline{E}| - D)\sqrt{|E - \overline{E}| - D}\right] + C(E - E_0)(E - E_3)$$



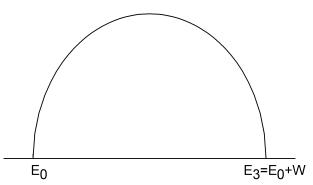
$$\overline{E} = (E_3 + E_0)/2$$
 ,  $W = E_3 - E_0$ 

$$B = C \left[ 2(E_3 - E_0) \sqrt{\frac{E_3 - E_0}{2} - D} \right]$$

To keep the oscillators simple and with 4 parameters only,  $M_0$ - $M_3$  and  $M_1$ - $M_2$  contributions to direct transitions are simulated by separate oscillators.

# Direct gap-Cody and Direct gap-Tauc (M<sub>0</sub>-M<sub>3</sub>)





$$\chi_{2-dir-Cody}^{inf}(E) = \frac{C}{K_{Cd}} \sqrt{(E - E_0)(E_3 - E)}$$

$$\chi_{2-dir-Tauc}^{inf}(E) = \frac{C}{K_{Td}} \frac{\sqrt{(E - E_0)(E_3 - E)}}{E^2}$$

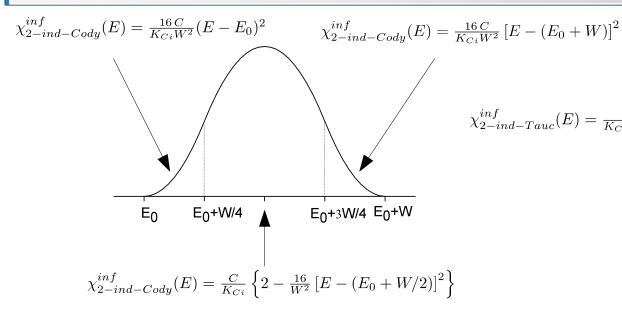
$$K_{Cd} = \frac{\pi}{16} W^2 (2E_0 + W)$$

$$K_{Td} = \frac{\pi}{2} (2E_0 + W - 2\sqrt{E_0(E_0 + W)})$$

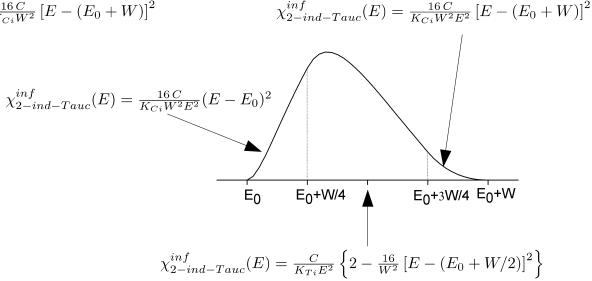
$$\int_0^\infty \epsilon_2^{osc}(E) E dE = C$$

# Indirect gap-Cody and Indirect gap-Tauc





$$K_{Ci} = E_0 W + \frac{W^2}{2}$$



$$f(r) = 2\left[8r^2ln\left(\frac{4r+1}{4r}\right) + 8(r+1)^2ln\left(\frac{4r+4}{4r+3}\right) - (1+8(r^2+r))ln\left(\frac{4r+3}{4r+1}\right)\right]$$

 $K_{Ti} = f(E_0/W)$ 

 $E_0$  is the gap energy, W is the absorption band width

## The convolution approach



The analytical expressions for  $\tilde{\chi}(E)$  are obtained by performing the convolution between a suitable  $\chi_2^{inf}$  calculated for infinite lifetime and the normalized complex  $\tilde{\chi}_{qo}$  describing the response of a quantum oscillator:

$$\tilde{\chi}(E) = \int \chi_2^{inf}(E_r) \tilde{\chi}_{qo}(E_r - E) dE_r$$

The function  $\tilde{\chi}_{qo}$  is given by the expression given before, normalized so that the integral of its imaginary part is equal to 1:

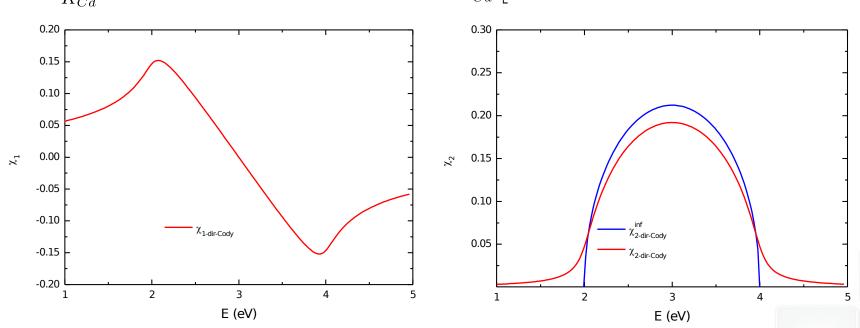
$$\tilde{\chi}_{qo}(E, E_r) = \frac{1}{\pi} \left[ \frac{1}{E_r - E + iD} \right]$$

The result of the convolution can be expressed as analytical functions in the four previous cases.

### Direct gap Cody - Lorentzian tail



convolution with  $\tilde{\chi}_{qo}$   $\chi_{2-dir-Cody}^{inf}(E) = \frac{C}{K_{Cd}} \sqrt{(E-E_0)(E_3-E)} \stackrel{\downarrow}{\longleftarrow} \tilde{\chi}_{dir-Cody}(E) = \frac{C}{K_{Cd}} \left[ \frac{E_0+E_3}{2} - E + iD - \sqrt{E_0-E+iD} \sqrt{E_3-E+iD} \right]$ 



The example in this figure has: C=1,  $E_0=2$  eV,  $W=E_3-E_0=2$  eV, D=0.1 eV.



## Direct gap Tauc - Lorentzian tail



The convolution between the  $\chi_{2-dirTauc}^{inf}$  and the normalized complex  $\tilde{\chi}_{qo}$  gives:

$$\chi_{1-dir-Tauc}(E) = \frac{C}{2DK_{Td}} \Re \left\{ \frac{1}{2(D-iE)} \left( 2iD + 2E - 2\sqrt{E_0E_3} - (i-1)\sqrt{2}\sqrt{D-i(E-E_0)}\sqrt{-iD-E+E_3} \right) \right.$$

$$\left. + \frac{1}{2(D+iE)} \left( -2iD + 2E - 2\sqrt{E_0E_3} + (i+1)\sqrt{2}\sqrt{D+i(E-E_0)}\sqrt{iD-E+E_3} \right) \right.$$

$$\left. + E(D-iE)^2\sqrt{D+i(E-E_0)}\sqrt{D+i(E-E_3)} / \left( D^2 + E^2 \right)^2 + E(D+iE)^2\sqrt{D-i(E-E_0)}\sqrt{D-i(E-E_3)} / \left( D^2 + E^2 \right)^2 \right.$$

$$\left. - ED \left( D^2(E_0 + E_3) + E(-4E_0E_3 + E(E_0 + E_3)) \right) / \left( \left( D^2 + E^2 \right)^2 \sqrt{E_0E_3} \right) \right\}$$

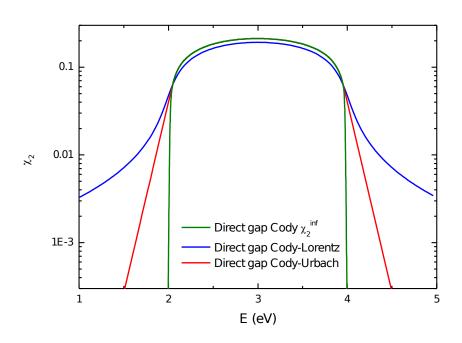
$$\chi_{2-dir-Tauc}(E) = \frac{CD}{K_{Td}}$$

$$\times \Re \left\{ -\left[ (D-iE)^2 \sqrt{D+i(E-E_0)} \sqrt{D+i(E-E_3)} \right] / \left( 2D \left( D^2 + E^2 \right)^2 \right) - \left[ (D+iE)^2 \sqrt{D-i(E-E_3)} \sqrt{D-i(E-E_0)} \right] / \left( 2D \left( D^2 + E^2 \right)^2 \right) + D \left[ D^2(E_0 + E_3) + E(-4E_0E_3 + E(E_0 + E_3)) \right] / \left( 2D \left( D^2 + E^2 \right)^2 \sqrt{E_0E_3} \right) \right\}$$



### Direct and Indirect gap oscillators with Urbach tail





 $\chi_2^{inf}$  is modified adding an Urbach tail on both band edges. The real part  $\chi_1$  is then obtained by means of the numerical integration of the Kramers-Kronig relation:

$$\chi_1(E) = \frac{2}{\pi} \mathcal{P} \int_0^\infty \frac{\chi_2(x)x}{x^2 - E^2} dx$$

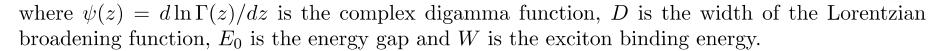
The parameters are: C=1,  $E_0 = 2$  eV, W = 2 eV, D = 0.1 eV. D corresponds to the quantum oscillator line width in one case and to the characteristic energy D of the Urbach tail  $(\chi_2(E) \propto exp(\pm E/D))$  in the other one.

## Direct gap Tauc-exciton



The oscillator included in kSEMAWc is based on an improved version of the Elliott's theory presented by Tanguy in 1995 [1] which gives a very compact expression for the susceptibility of a semiconductor with a direct gap in the Tauc approximation taking into account the excitons and a Lorentzian broadening of the states:

$$\tilde{\chi}(E) = \frac{C\sqrt{W}}{(E+iD)^2} \left[ g_a(\xi(E+iD)) + g_a(\xi(-E-iD)) - 2g_a(\xi(0)) \right]$$
$$g_a(\xi) = 2\ln\xi - 2\pi\cot(\pi\xi) - 2\psi(\xi) - 1/\xi$$
$$\xi(z) = \sqrt{\frac{W}{E_0 - z}}$$



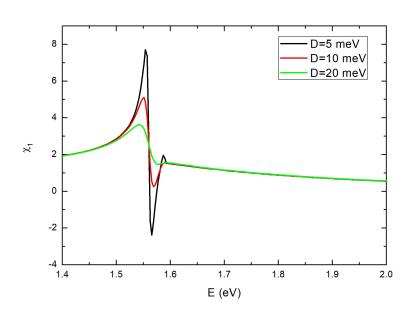
[1] C. Tanguy, Optical dispersion by Wannier excitons, Phys. Rev. Lett. 75, 4090–4093 (1995).

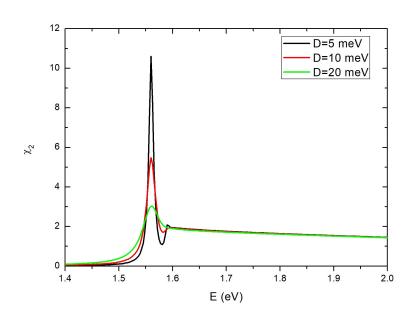
 $E_{\infty} = E_{\Omega}$ 

## Direct gap Tauc-exciton: broadening effect



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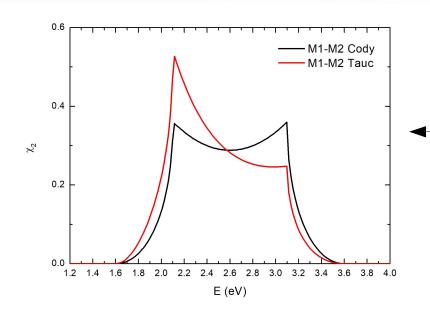




The other parameters are: C=4,  $E_0 = 1.6 \text{ eV}$ , W = 40 meV.

# 3D M<sub>1</sub>-M<sub>2</sub> critical point oscillator





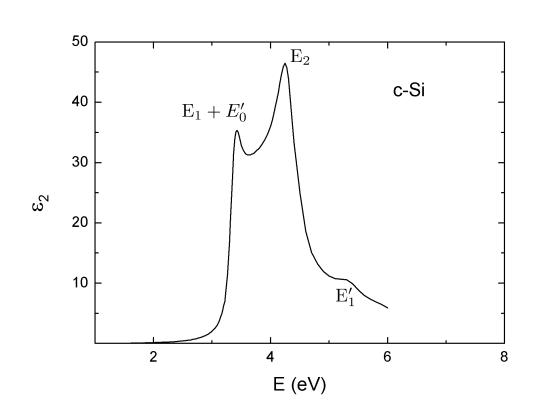
Plot of  $\chi_2$  for a M<sub>1</sub>-M<sub>2</sub> oscillators with C=1  $eV^2$ ,  $E_0 = 1.6$  eV, W = 2eV and D=0.5 eV using the Cody (black curve) and Tauc (red curve) approximations.

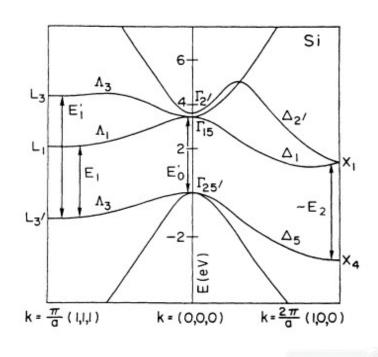
The real part  $\chi_1$  is obtained by means of the numerical integration of the Kramers-Kronig relation.

$$\chi_{2-CM12}(E) = \frac{C}{K_{CM12}} \left\{ K_1 \left[ \sqrt{\frac{W}{2} - D} - \Theta(|E - \overline{E}| - D) \sqrt{|E - \overline{E}| - D} \right] + (E - E_0)(E - E_3) \right\}$$

## A familiar case: crystalline silicon

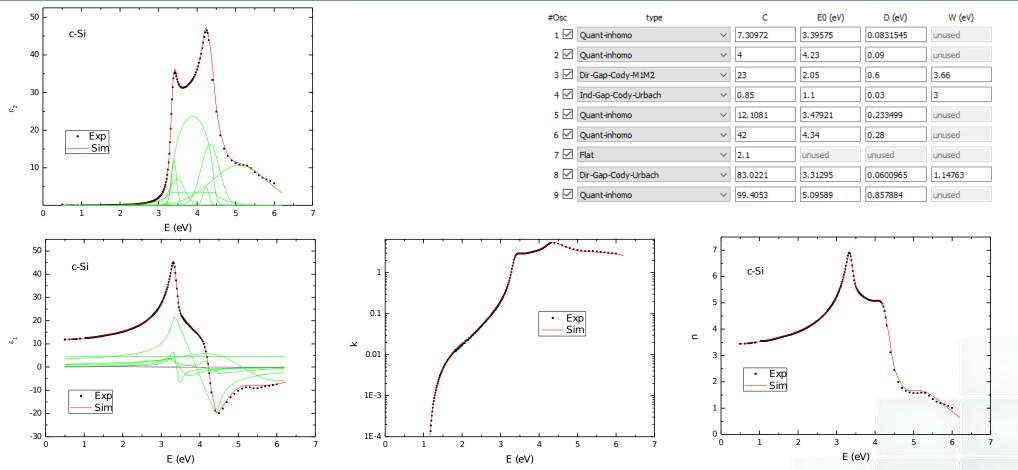






## A familiar case: crystalline silicon

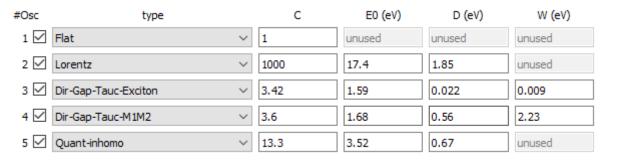


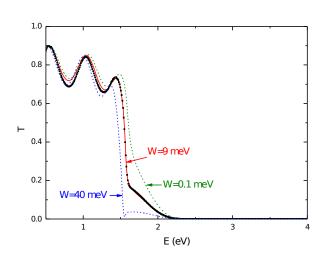


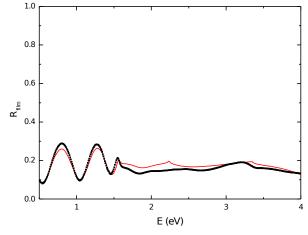
# Perovskite film on glass

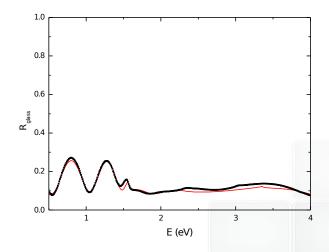


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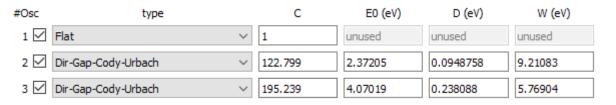


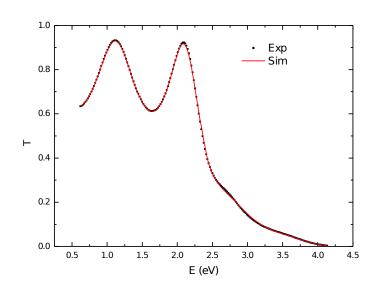


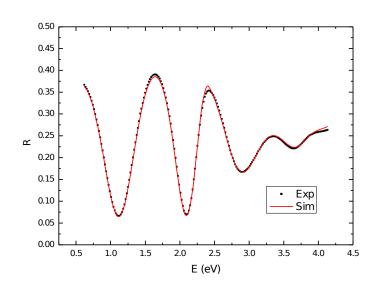


## ZnSe film on glass









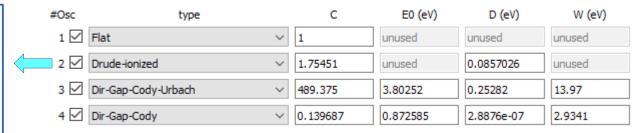
### IWO film on glass

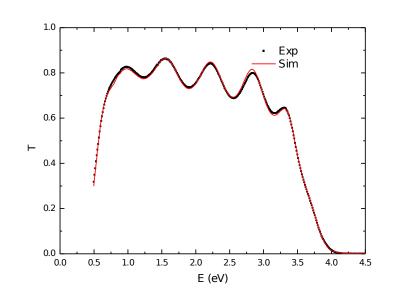


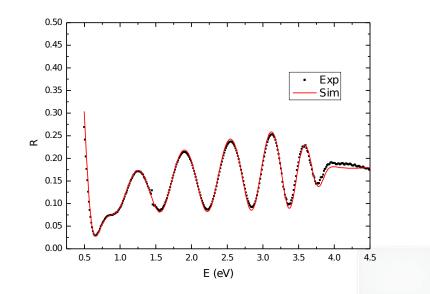
From Drude parameters, using  $m^* = 0.35m_e$ , we get:

$$N(\text{cm}^{-3}) = C(\text{eV}^2) \frac{m^*}{m_e} 4.617 \cdot 10^{20} = 2.83 \cdot 10^{20} \text{cm}^{-3}$$

$$\mu \left(\frac{cm^2}{Vs}\right) = \frac{1.159}{D(eV)m^*/m_e} = 38.5 \left(\frac{cm^2}{Vs}\right)$$

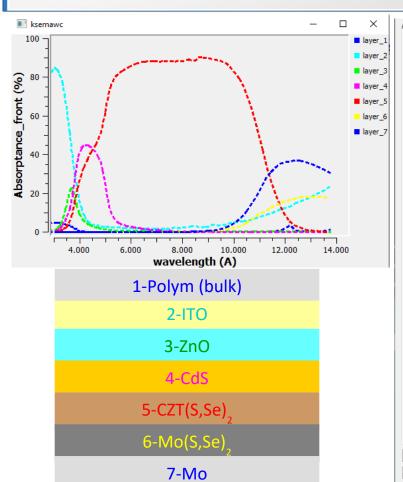






### CZTSSe solar cell

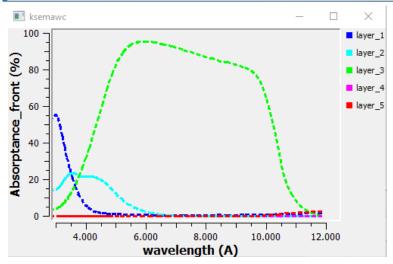




|             |                                 | crice (ii oiii i            | ront to Back) |           |            |                         |            |                              |            |             |              |    |
|-------------|---------------------------------|-----------------------------|---------------|-----------|------------|-------------------------|------------|------------------------------|------------|-------------|--------------|----|
| type        |                                 | Mo                          | ve            | d(mm-A)   | rough (A)  | GRAD-n                  | dGRAD-n/dE | CURV-n                       | GRAD-k     | CURV-k      | material     |    |
| ulk         | ~                               | -                           | dw            | 0.10      | 0.0        | 0.0000 💠                | 0.000      | 0.0000                       | 0.0000     | 0.0000      | Material #6  | ~  |
| omo. film   | ~                               | up                          | dw            | 2400.00   | 500.0      | 0.0000                  | 0.000      | 0.0000                       | 0.0000     | 0.0000      | Material #3  | ~  |
| omo. film   | ~                               | up                          | dw            | 500.00    | 0.0        | 0.0000                  | 0.000      | 0.0000                       | 0.0000     | 0.0000      | Material #5  | ~  |
| omo. film   | ~                               | up                          | dw            | 800.00    | 0.0        | 0.0000                  | 0.000      | 0.0000                       | 0.0000     | 0.0000      | Material #4  | ~  |
| omo. film   | ~                               | up                          | dw            | 10000.00  | 1000.0     | 0.0000                  | 0.000      | 0.0000                       | 0.0000     | 0.0000      | Material #8  | ~  |
| omo. film   | ~                               | up                          | dw            | 2500.00 🕏 | 0.0        | 0.0000                  | 0.000      | 0.0000                       | 0.0000     | 0.0000      | Material #7  | ~  |
| omo. film   | ~                               | up                          | dw            | 5000.00   | 0.0        | 0.0000                  | 0.000      | 0.0000                       | 0.0000     | 0.0000      | Material #2  | ~  |
| ulk         | ~                               | up                          | dw            | 0.00      | 0.0        | 0.0000                  | 0.000      | 0.0000                       | 0.0000     | 0.0000      | Material #1  | V  |
| ulk         | ~                               | up                          | -             | 0.00      | 0.0        | 0.0000                  | 0.000      | 0.0000                       | 0.0000     | 0.0000      | Material #1  |    |
| layers 7    |                                 | Symmetric on 2nd face inhon |               |           |            | geneity as 23 sub       | film c     | computing <f(x)> with</f(x)> | N= 5 -     | Plot Exp Me | as ! Simulat | e! |
| aterials    |                                 |                             |               |           |            |                         |            |                              |            |             |              |    |
| Material #  | 1                               | unknown                     |               |           | n          | k                       | wi         | th                           | EN         | 1A          | f            |    |
| Material #  | 2                               | CZTSSe cells/Mo ENEA        |               |           |            | . 0                     |            | a                            | r n=1 k=0  | ~           | 0.000        | 4  |
| Material #  | 3                               | CZTSSe cells/ITO standard   |               |           |            | . 0                     |            | a                            | r n=1 k=0  | 0.000       | 4            |    |
| Material #  | 4                               | CZTSSe cells/CdS ENEA V     |               |           |            | . 0                     |            | a                            | r n=1 k=0  | 0.000       | 4            |    |
| Material #  | 5                               | CZTSSe cells/ZnO ENEA V     |               |           |            | . 0                     |            | a                            | r n=1 k=0  | 0.000       | À            |    |
| Material #6 | 6                               | CZTSSe cells/Polym IPC 1L 0 |               |           | <b>v</b> 1 | . 0                     |            | a                            | r n=1 k=0  | 0.000       | À            |    |
| Material #  | 7                               | CZTSSe cells/MoSeS2 Richter |               |           | <b>v</b> 1 | . 0                     |            | a                            | ir n=1 k=0 | 0.000       | A T          |    |
| Material #  | #8 CZTSSe cells/CZTSSe Gokmen V |                             |               | <b>v</b>  | . 0        |                         | a          | ir n=1 k=0                   | ~          | 0.000       | 4            |    |
| output SF   |                                 |                             |               |           | V 1        | . 0                     |            | a                            | ir n=1 k=0 | ~           | 0.000        | 4  |
| input SF    |                                 | constant nk V               |               |           | v 1        | . 0                     |            | air n=1 k=0                  |            |             | 0.000        | 4  |
| input PDS   | t PDS constant nk               |                             |               | v 1       | . 0        |                         | а          | r n=1 k=0                    | ~          | 0.000       | À            |    |
| input ELI-1 | I-1 constant nk 🗸               |                             |               | v 1       | . 0        |                         | a          | r n=1 k=0                    | ~          | 0.000       | 4            |    |
| input ELI-2 |                                 |                             |               | v 1       | . 0        |                         | a          | r n=1 k=0                    | ~          | 0.000       | 4            |    |
| input ELI-3 |                                 |                             |               |           | v 1        | . 0                     |            | a                            | r n=1 k=0  | ~           | 0.000        | 4  |
| input ELI-4 | 4                               | constant nk                 | :             |           | v 1        | . 0                     |            | a                            | r n=1 k=0  | ~           | 0.000        | 4  |
|             |                                 | e Spi! CZ                   |               |           |            | cell with a 100 um fror |            |                              |            |             |              |    |

## HJ c-Si solar cell





| 1-ITO    |  |
|----------|--|
| 2-a-Si:H |  |
| 3-c-Si   |  |
| 4-a-Si:H |  |
| 5-ITO    |  |

| odel of the optical d<br>type |               | ove                | d(mm-A)    | rough (A)  | GRAD-n   | dGRAD-n/dE | CURV-n | GRAD-k     | CURV-k   | materia     | al |
|-------------------------------|---------------|--------------------|------------|------------|----------|------------|--------|------------|----------|-------------|----|
| omo. film                     |               | dw                 | 690.00     | 0.0 💠      | 0.0000   | 0.000      | 0.0000 | 0.0000     | 0.0000   | Material #2 |    |
| omo, film 🔻                   | up            | dw                 | 120.00     | 0.0        | 0.0000 🗘 | 0.000      | 0.0000 | 0.0000     | 0.0000   | Material #3 |    |
| omo, film V                   |               | dw                 | 2500000.00 | 1000.0     | 0.0000   | 0.000      | 0.0000 | 0.0000     | 0.0000   | Material #4 |    |
| omo, film                     |               | dw                 | 150.00     | 0.0        | 0,0000   | 0.000      | 0.0000 | 0.0000     | 0.0000   | Material #3 |    |
| omo, film                     |               | dw                 | 690.00 🗘   | 0.0 🗘      | 0.0000   | 0.000      | 0.0000 | 0.0000     | 0.0000   | Material #2 |    |
| ulk v                         | up            | dw                 | 0.00 🗘     | 0.0        | 0.0000   | 0.000      | 0.0000 | 0.0000     | 0.0000   | Material #1 |    |
|                               |               |                    |            | 0.0        |          | 0.000      |        | 0.0000     |          |             |    |
| ulk ~                         | up            | dw                 |            |            | 0.0000 💠 |            |        |            | 0.0000   | Material #1 |    |
| ulk v                         | up            | dw                 | 0.00       | 0.0        | 0.0000   | 0.000      | 0.0000 | 0.0000     | 0.0000   | Material #1 |    |
| ulk \                         | up            | -                  | 0.00       | 0.0        | 0.0000 💠 | 0.000      | 0.0000 | 0.0000     | 0.0000 💠 | Material #1 |    |
| terials<br>Material #1        | unknown       |                    |            | n          | k        | v          | vith   | EM         | A        | f           |    |
| Material #2                   | ITO/ITO st    | andard             |            | v 1        | 0        |            | ē      | ir n=1 k=0 | ~        | 0.000       |    |
| Material #3                   | HJ stack/a    | stack/a-SiH CNR V  |            |            | 0        |            | a      | ir n=1 k=0 | ~        | 0.000       |    |
| Material #4                   | sili/cSixx.1  |                    |            | <b>v</b> 1 | 0        |            | ā      | ir n=1 k=0 | ~        | 0.000       |    |
| Material #5                   | constant nk   | constant nk 🗸      |            |            | 0        |            | ž.     | ir n=1 k=0 | ~        | 0.000       |    |
| Material #6                   | constant nk   | constant nk v      |            |            | 0        |            | a      | ir n=1 k=0 | ~        | 0.000       |    |
| Material #7                   | constant nk   | constant nk $\lor$ |            |            | 0        |            | ā      | ir n=1 k=0 | ~        | 0.000       |    |
| Material #8                   | constant nk   | constant nk 🔍      |            |            | 0        |            | a      | ir n=1 k=0 | ~        | 0.000       |    |
| output SF                     | constant nk   |                    |            | v 1        | 0        |            | a      | ir n=1 k=0 | ~        | 0.000       |    |
| input SF                      | constant nk   |                    |            | v 1        | 0        |            | a      | ir n=1 k=0 | ~        | 0.000       |    |
| input PDS                     | constant nk   | :                  |            | v 1        | 0        |            | a      | ir n=1 k=0 | ~        | 0.000       |    |
|                               | constant nk   | constant nk v      |            |            | 0        |            | a      | ir n=1 k=0 | ~        | 0.000       |    |
| input ELI-1                   | constant nk v |                    |            | v 1        | 0        |            | a      | ir n=1 k=0 | ~        | 0.000       |    |
| input ELI-1<br>input ELI-2    | constant nk 🗸 |                    |            | v 1        | 0        |            | ā      | ir n=1 k=0 | ~        | 0.000       |    |
|                               | constant nk   |                    |            |            |          |            |        |            |          |             |    |

### Acknowledgements



Besides Marco Montecchi and Alberto Mittiga many peoples helped in the kSEMAWc development. We thank:

- Claudia Malerba and Francesca Menchini for their work in testing and improving kSEMAWc to characterize semiconductor materials
- Enrico Nichelatti for the wise search for analytical solutions of the integrals on the density of the states, as well as for the LATEX revision of the manual
- Francesco Biccari for his useful suggestions for simplifying the software distribution
- Luca Serenelli for his support in outlining the Linux installation procedure
- Giacomo Mazzamuto for his support in the compilation and linking of the GSL library under Windows

#### And...Thank You for your attention!

This research was financially supported by:

- EU H2020 research and innovation programme under the grant agreement 823802 (SFERA-III)
- EU H2020 research and innovation programme under the grant agreement 952982 (Custom-Art)
- the Italian Ministry of Economic Development in the framework of the Operating Agreement with ENEA for the Research on the Electric System.

